

Power Loss Estimation for PWM and Soft-switching Inverter using RDCLI

Sushant kumar Pattnaik and K. K. Mahapatra

Abstract— The inspiration for the use of the resonant inverter shoots from an aspiration to minimise the switching losses in the inverter devices. This paper portrays an exhaustive study on losses in the resonant DC link inverter. Equations for accessing the diverse losses in the resonant DC link inverter and a corresponding hard switching inverter are developed. Based on these equations, a design optimization is executed for the DC link inverter to attain the optimum standards of the link components. Finally, an evaluation of the losses in the resonant inverter and the hard switching inverter is presented.

Index Terms— Power Loss, PWM Inverter, Resonant DC Link Inverter, Soft-Switched Inverter.

I. INTRODUCTION

PWM (Pulse Width Modulation) Inverters and Soft-Switching Inverters (SSI) are used in power electronics literature extensively. Both classes of inverters find applications in several domains. Soft-Switching Inverters are developed in recent times primarily to reduce switching losses. Both PWM and SSI inverters provide a different advantages vis-à-vis disadvantages which are documented in the literature [1]-[9]. In this paper an attempt is made to evaluate losses in both types of inverters. This would facilitate for optimum design of link components in the Resonant DC Link Inverter (RDCLI). Here a detailed analysis of the losses in the resonant DC link inverter is made. Equations for estimating the various losses in the resonant DC link inverter and an equivalent hard switching inverter are developed. Based on these equations, a design optimization is performed for the resonant DC link inverter to find the optimum values of the link components. Finally, a comparison of the losses in the resonant inverter and hard switching inverter is made.

The rest of this paper is compiled as follows. Various losses associated with the hard switching inverter is discussed in section II. Losses due to Soft-switching Inverters are discussed is presented in section III. Resonant Inductor loss is briefed in section IV. In section V System Optimization is made and Graphs & Results are discussed. Finally a conclusion is drawn in section VI.

Manuscript received on December 1, 2009. This work was supported by Ministry of Communication and Information Technology, Government of India.

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II. LOSSES IN THE HARD SWITCHING INVERTER

The key power losses, in the hard switching inverter, are the conduction and switching losses in the inverter devices. Occurrence of the conduction losses is due to the declining voltage across the device as well as the current flow through the device striking in chorus. Switching losses are sustained by the concurrent occurrence of voltage and current on the device while switching. Evaluation of these losses can be done using simplified device models.

A. Conduction Losses

To evaluate conduction loss, the device is simplified as a constant voltage drop in series with a linear resistor. For both IGBTs and diodes, this simplified model is appropriate. The expression for the on-state voltage of an IGBT and a diode is shown in Equations 1.1 and 1.2, respectively.

$$V_{ce} = V_q + I_q \cdot R_q \quad (1.1)$$

$$V_{ak} = V_d + I_d \cdot R_d \quad (1.2)$$

I_q and I_d denotes the current flowing through the IGBT and diode, respectively. V_{ce} and V_{ak} denote the voltage across the IGBT and Diode. The parameters, V_q , R_q , V_d , and R_d can be extracted from data sheets. Powers dissipated in a component with a constant voltage drop correspond to the average current times the voltage drop. The rms current squared times the resistance signifies the power dissipated in a resistor. To ease the calculation of the IGBT and diode currents, the load current is assumed to be sinusoidal. Calculating the average and rms currents of the IGBT and diode in an inverter (given sinusoidal pulse width modulation), using Equations 1.3 to 1.6 [6].

$$I_q(\text{avg}) = I_o(pk) \left[\frac{1}{2\pi} + \frac{m_a \cos \phi}{8} \right] \quad (1.3)$$

$$I_q(\text{rms}) = I_o(pk) \sqrt{\frac{1}{8} + \frac{m_a \cos \phi}{3\pi}} \quad (1.4)$$

$$I_d(\text{avg}) = I_o(pk) \left[\frac{1}{2\pi} - \frac{m_a \cos \phi}{8} \right] \quad (1.5)$$

$$I_d(\text{rms}) = I_o(pk) \sqrt{\frac{1}{8} - \frac{m_a \cos \phi}{3\pi}} \quad (1.6)$$

Where $I_o(pk)$ denotes the peak load current, ϕ denotes the power factor angle, and m_a denotes the modulation index. With the simplified models, the conduction losses in the

IGBT, P_{q-con} , diode, P_{d-con} are obtained using Equations 1.7 and 1.8.

$$P_{q-con} = V_q \cdot I_q (avg) + R_q \cdot I_q (rms)^2 \quad (1.7)$$

$$P_{d-con} = V_d \cdot I_d (avg) + R_d \cdot I_d (rms)^2 \quad (1.8)$$

The total conduction losses, $P_{tot-con}$ of 4 IGBTs and diodes are given by Equation 1.9.

$$P_{tot-con} = 4(P_{q-con} + P_{d-con}) \quad (1.9)$$

Evidently, considering device characteristics, the conduction losses are only reliant on load conditions.

B. Switching Losses

Three components of the switching losses in the hard switching inverter can be identified; IGBT turn on losses, IGBT turn off losses, and the losses due to diode reverse recovery. Evaluation of the switching losses in the hard switching inverter can be done using the measured values of switching energy from the data sheets.

Generally, data sheets provide the calculated values of turn-on and turn-off energy (E_{on} and E_{off}) for a conventional test voltage and current (V_{test} and I_{test}). The calculated values of turn-on energy comprise the losses due to diode reverse recovery. These standards should be leveled suitably for a specific application using Equation 1.10 [7].

$$E_{tot} = K_g \cdot (E_{on} + E_{off}) \cdot \frac{V_s}{V_{test}} \cdot \frac{I_0(pk)}{I_{test}} \quad (1.10)$$

Equation 1.10 represents V_s as the bus voltage, $I_0(pk)$ as the peak load current, and K_g as the correction factor to account for the gate drive impedance. Calculation for the total switching losses, P_{tot-sw} , switching inverter can be done using Equation 1.11 [6].

$$P_{tot-sw} = 4 f_s \cdot \frac{E_{tot}}{\pi} \quad (1.11)$$

where f_s denotes the PWM switching frequency. Equation 1.12 in the hard switching inverter as the total losses given in is the sum of the total conduction and switching losses.

$$P_{tot}(HSI) = P_{tot-con} + P_{tot-sw} \quad (1.12)$$

Evidently, from Equation 1.11 the switching losses in the hard switching inverter are directly related to the PWM switching frequency. Hence due to the switching losses the achievable switching frequency is thermally limited. Further, from Equation 1.10 the switching energy is proportional to the voltage across the device during switching. Visibly, the switching losses can be eliminated if the voltage across the device is zero during the switching.

III. SOFT SWITCHING LOSSES

A principal matter concerned with the evaluation of loss for the resonant DC link inverter is to calculate the switching losses in the device under zero voltage switching. Behavioural characteristics of IGBTs under zero voltage switching fluctuate considerably from that under hard switching conditions [10]. In the resonant inverter, the devices are turned on only when the anti-parallel diodes are conducting; thus no dynamic saturation exists at device turn on. The higher peak voltage and current stresses resulting from diode recovery are also no longer relevant. The turn-on losses of device and the losses due to diode recovery are negligible, consequently, only the turn-off losses need to be considered [11].

Let us assume an IGBT is carrying a current I_Q which is switched off in a zero voltage switching circuit as shown in Figure 1.1; the difference between I_Q and the instantaneous device current flows into a resonant capacitor, C_r , connected directly in parallel to the device. This current determines the voltage waveform. An IGBT turn-off waveform for such a case is illustrated in Figure 1.2a. The turn-off current of the IGBT is characterized by a sharp decrease in current, taking only about 50ns for a 50A/600V IGBT. This is a result of the MOSFET part of the IGBT turning off. The bipolar part is still conducting, but the carriers are swept away quickly by tail current. The complete fall time, t_f , is about 550ns for the 50A/600V IGBT.

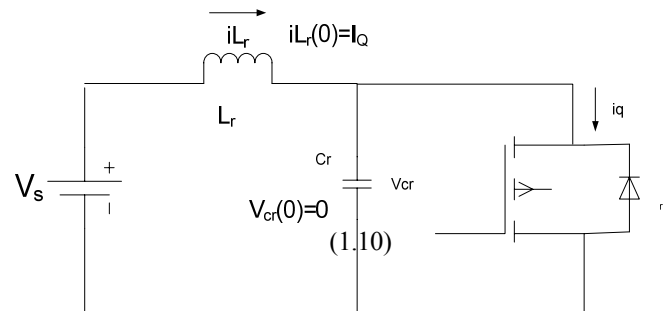


Fig. 1.1 A zero voltage switching circuit for characterizing IGBT turn-off behaviour

Figure 1.2b shows a simplified model of this switching behavior. Here β denotes a break point of the IGBT current waveform. The value of β ranges from 0.25 to 0.3, obtained from the extensive experimental tests of IGBTs under the zero voltage switching conditions [10]. Considering time t_{tail} as the end of the current flow rather than the fall time, t_f , where the current is still 10% of I_Q . Under these assumptions, the initial current in the resonant capacitor is $(1-\beta) I_Q$, and the IGBT current decreases linearly from βI_Q to zero taking the time of t_{tail} . The differential equations 1.13 and 1.14 govern the circuit behavior after the IGBT is switched off.

$$i_{L_r} = C_r \frac{dv_{cr}}{dt} + \frac{\beta I_Q}{t_{tail}} (t_{tail} - t) \quad (1.13)$$

$$L_r \frac{di_{L_r}}{dt} = V_s - v_{cr} \quad (1.14)$$

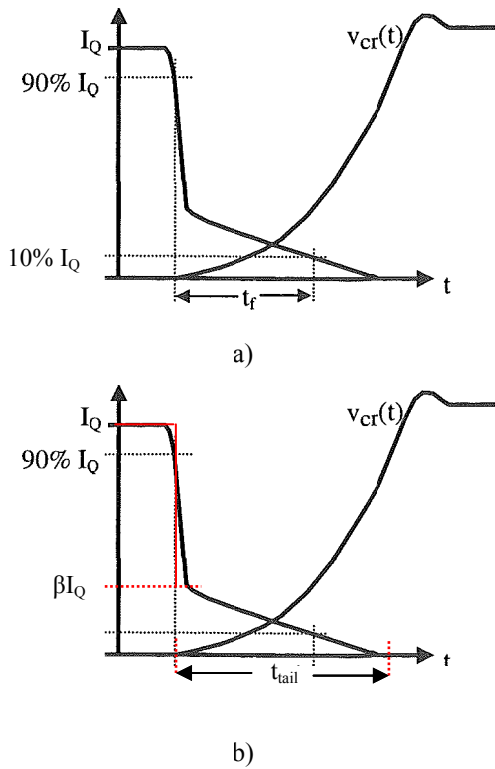


Fig. 1.2 (a) Realistic IGBT turn-off waveforms under zero-voltage switching,
(b) Idealized model for calculation of soft-switching losses

Solving Equations 1.13 and 1.14 with the initial conditions, $i_{Lr}(0) = I_Q$ and $v_{cr}(0) = 0$, the expression for the bus voltage with the impact of the tail current taken into account is found and given in Equation 1.15.

$$v_{cr}(t) = (1 - \beta) I_Q Z_r \sin \omega t + (1 - \cos \omega t) \left(V_s + \frac{\beta I_Q L_r}{t_{tail}} \right) \quad (1.15)$$

Multiplying this voltage with the device current and integrating up to t_{tail} yields an expression for the turn-off energy for the IGBT carrying the current I_Q as given in Equation 1.16 [10].

$$E_{off}(I_Q) = Z_r I_Q^2 \beta (1 - \beta) \left(\frac{1}{\omega} - \frac{\sin \omega t_{tail}}{\omega^2 t_{tail}} \right) + \left(V_s \beta I_Q + \frac{\beta^2 I_Q^2 L_r}{t_{tail}} \right) \left[\frac{t_{tail}}{2} - \frac{(1 - \cos \omega t_{tail})}{\omega^2 t_{tail}} \right] \quad (1.16)$$

It is noticed from Equation 1.15 the rate of the increase of the bus voltage is mainly governed by the resonant impedance, therefore, the turn-off energy given in Equation 1.16 is directly related to the resonant impedance. At a specified resonant frequency, a smaller value of the resonant impedance indicates a larger value of the resonant capacitance, and gives a slower rise of the bus voltage when the tail current still persists and results in lower turn-off losses. With turn-off energy calculated, switching losses can

then be found by multiplying turn-off energy with the switching frequency.

IV. LOSSES IN THE RESONANT INVERTER

Conduction and switching losses in the five devices and losses in the ESRs of the resonant link aggregates to form the total losses in the resonant inverter. Calculations for these losses are done individually.

A. Main Device Conduction Loss

In view of the fact that there is a minimal involvement of the main devices with the link resonance, the conduction losses in the main IGBTs (S_1 - S_4) and diodes (D_1 - D_2) are almost autonomous of the link components. The resonant inverter modulated by the synchronized PWM act almost exactly like the hard switching PWM inverter manoeuvring off the same supply voltage; it is written off as the same output voltage to the supply voltage ratio. Thus, under the same load conditions and for the same devices, the conduction losses of main IGBTs and diodes in the resonant inverter, $P_{main-con}$ are almost the same as in the hard switching inverter given by Equation 1.9 and are re-expressed as Equation 1.17.

$$P_{main-con} = 4(P_{q-con} + P_{d-con}) \quad (1.17)$$

B. Main Device Switching Loss

Primarily the switching losses in the main devices depend on the resonant capacitor and indirectly on the resonant inductor. As explained in Section 1.2, only turn-off switching losses need to be considered. Turned-off the peak load current, $I_0(pk)$, in a main device, the resulting turn-off energy, $E_{off}[I_0(pk)]$, can be calculated using Equation 1.16 with I_Q replaced by $I_0(pk)$. In the resonant inverter, the switching frequency of the main devices varies and depends mainly on the resonant frequency f_r , whenever the output voltage is zero volts, highest switching frequency occurs, and equals the resonant frequency. The average switching frequency of the main devices equals half the resonant frequency [13]. The switching losses in the four main devices, $P_{main-sw}$, can be found using Equation 1.18.

$$P_{main-sw} = 4 \frac{f_r}{2} E_{off}[I_0(pk)] \quad (1.18)$$

C. ESR Losses

Since the current circulates in the resonant link, losses are gained in ESR elements. The ESR losses in the resonant capacitor can be ignored since the resonant capacitor has a very high quality factor. Also, the ESR losses in the clamp capacitor can be neglected since the rms current in the clamp capacitor is very low. Hence, only the ESR losses in the resonant inductor need to be considered.

When the resonant inverter operates with a load, the inductor current oscillates tracking the changes of the inverter DC current. The inductor current waveform [14] is given by Equation 1.19

$$I_r(t) = -\frac{1}{\phi_{12}}[\theta_{12}I_0 + \theta_{12}V_s] \quad (1.19)$$

The ESR value of the resonant inductor is dogged by the inductor quality factor Q . The losses in the resonant inductor, P_{L_r} , are then achieved using Equation 1.20.

$$P_{L_r} = \frac{Z_r}{Q} I_r^2 \quad (1.10)$$

The total losses in the Resonant DC link inverter can now be calculated by adding up the main device losses and the resonant inductor losses, and are represented in Equation 1.21.

$$P_{tot} = P_{main-con} + P_{main-sw} + P_{L_r} \quad (1.21)$$

V. SYSTEM OPTIMIZATION

The design of the resonant DC link inverter initiates with the selection of the switching devices. Given the device characteristics, the resonant components L_r and C_r can then be preferred to minimize the total losses.

Five-pack 50A/600V IGBT modules (Mitsubishi) are chosen as the main devices of the inverter stage and device of the resonant link.

Limitations to the maximum resonant frequency achievable in the real circuit by several factors include device switching characteristics, thermal constraints, and availability of the passive components [15]. To modulate the inverter for the prototype resonant DC link inverter, a synchronized PWM scheme is used. In this scheme the PWM signals are sampled at the resonant frequency and then synchronized to the zero crossing of the bus voltage. For example, hysteresis bang-bang control is used in PWM inverters for current control within the inverter; however RDCLI uses zero hysteresis bang-bang control; if switches are switched only when the voltage/current is zero and not necessarily when bang-bang controller acts. In order to preserve the well-defined switching pattern of the PWM signals, simulations show that a resonant frequency of about 5 times of the PWM switching frequency is adequate. A resonant frequency of 25-40 kHz is chosen for the design of the link components, considering a maximum PWM switching frequency of 5-8 kHz. If the resonant impedance is known, considering the resonant frequency, the values of the resonant components can be determined.

Under no load in the resonant link, losses are regulated by the resonant current, which is nearly verified by V_s/Z_r . A lower current in the resonant link and lower losses is resulted by a larger value of the resonant impedance. With the resonant inverter under load, the load-dependent DC current flows through the resonant inductor. A larger value of the resonant impedance suggests a larger value of resonant inductance, and this in turn causes more ESR

losses in the inductor since more turns are required to build the inductor [Fig. 1.3(a)]. On the other hand when the inverter devices are switched off, for the inverter stage, a small value of the resonant impedance is desirable to make the bus voltage increase slowly. Evidently, an optimum value of the resonant impedance exists, which gives the lowest losses in the resonant DC link inverter.

A computer program has been developed, based on the equations derived in the previous sections, to calculate the total losses in the resonant inverter and hard switching inverter. Figure 1.3 shows design optimization curves for the resonant DC link inverter using IGBTs operated off the supply voltage of 230V. With the intention of calculating loss, the load is assumed to be a sinusoidal current source of 25A rms with a power factor of 0.86 and a modulation index of 0.65. A realistic inductor quality factor of 193 is used for the loss calculations. The model parameters, $V_q=0.78V$ and $R_q=0.011\Omega$, are used to calculate the conduction losses of the IGBTs. The model parameters, $V_d=1.0V$ and $R_d=0.009\Omega$, are used to calculate the conduction losses of the diodes. The values, $\beta=0.3$ and $t_{tail}=515ns$, are used to calculate the soft switching losses. Loss calculations are executed for the different values of the resonant impedance while the resonant frequency is stable at 28 kHz.

It is observed from Figure 1.3 that with a decrease in the resonant impedance the losses in the main devices and resonant inductor decrease, and hence total loss reduce. The load-dependent losses in the ESR of the inductor seem to be insignificant given a high quality factor, as can be seen there is only a small increase of the losses in the inductor while the value of the resonant impedance is increased. Examining the curve of the total losses, the trade-off between the link losses and the main devices' switching losses is clearly exhibited. The total losses in the resonant DC link inverter are very sensitive to the resonant impedance.

For the given application, the optimum value of the resonant impedance is chosen around 5.7. Given the resonant frequency of 28 kHz this value of the resonant impedance corresponds to a resonant inductance of 33 μ H and a resonant capacitance of 1 μ F. For the final implementation of the prototype resonant DC link inverter, the closest values of resonant inductance of 33 μ H and resonant capacitance of 1 μ F are used. This combination gives a value of resonant impedance of 6 and a natural resonant frequency of 27.71 kHz.

For a comparison, the losses in the hard switching inverter using the same IGBTs under the identical operating conditions are also calculated. The model parameters for the calculations of the conduction losses in the hard switching inverter are the same as those used for the resonant inverter. For the calculations of the switching losses in the hard switching inverter, the model parameters, $E_{on}=1.9mWs$, $E_{off}=4.1mWs$ (for $V_{test}=300V$, $I_{test}=50A$), and a gate drive correction factor K_g of 1.2, are used. The calculated results are summarized in Table 1.

It can be seen from Table 1 that for the resonant inverter the switching losses in the main devices are substantially reduced, and the conduction losses in the main devices are the major loss component. Under the identical load conditions, the resonant inverter has huge reduction in the main devices' switching losses by compared with the hard switching inverter operating at a PWM switching frequency of 5 KHz. Including the link losses, the resonant inverter still has reduction in the total power losses.

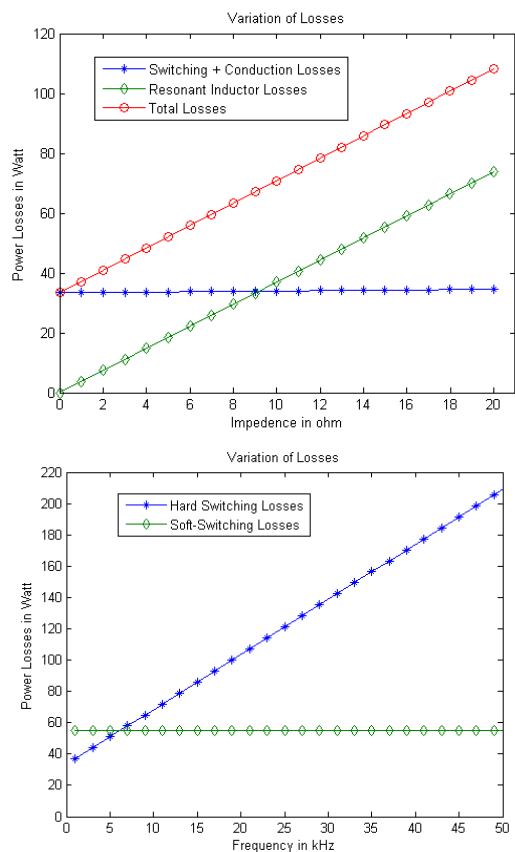


Fig. 1.3 Variation of the losses (a) in Resonant DC Link Inverter due to resonant Impedance, (b) wrt. Frequency,

The lower switching losses allow the resonant inverter to operate at a substantially higher switching frequency, and have a strong potential for realizing higher performance and power density. For the hard switching inverter, on the other hand, switching losses completely dominate the total losses at a high switching frequency of 15 kHz and limit any further increase of the switching frequency. At a low PWM switching frequency of 5 kHz the hard switching inverter is more efficient, where the switching losses are very low and the conduction losses are dominant.

We presented a detailed analysis of the losses in the resonant DC link inverter. The analysis shows that with the decrease of the resonant impedance the losses in the main devices and resonant link decrease. Using the overall losses as a criterion, the design optimization for the resonant DC link inverter intended for any industrial application yields an optimal value of the resonant impedance as 5.7. This impedance value corresponds to a combination of a resonant inductance of $33\mu\text{H}$ and a resonant capacitance of $1\mu\text{F}$. Loss calculations show that in the resonant inverter the switching losses in the main devices are substantially reduced, and the conduction losses become the major loss component. Under the identical expected load conditions there is significant reduction in the switching losses in the main devices and additionally there is reduction in total losses in comparison to the hard switching counterpart operating at a switching frequency of 15 kHz.

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TABLE 1
Calculated Losses in the HSI and Resonant DC Link Inverter

	Frequency (KHz)	Hard Switching(W)		Soft-switching (W)	Total Losses (W)
		Conduction	Switching	Inductor	
Hard switching	5	33.34	17.57		50.91
	10	33.34	35.14		68.48
	15	33.34	52.71		86.05
RDCLI	28	33.34	1.01	21.17	55.52

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